



Iranian Journal of Physics Research, Vol. 25, No. 2, 2025
DOI: 10.47176/ijpr.25.1.12039

Crystal growth and structural and piezoelectric characterizations of relaxor ferroelectric Mn:PIN-PMN-PT

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(Received 13 January 2025; in final form 21 May 2025)

Abstract

The relaxor ferroelectric single crystals of PMN-PT family have great potential for applications in piezoelectric actuators and transducers. In this paper, Mn:PIN-PMN-PT piezoelectric single crystal with the chemical formula $24[\text{Pb}(\text{Nb}_{1/2}\text{In}_{1/2})\text{O}_3]-42[\text{Pb}(\text{Mg}_{1/3}\text{Nb}_{2/3})\text{O}_3]-34\text{PbTiO}_3$ doped with 2 mol% Mn, with a diameter of 2 and a length of 5 cm was grown using the Bridgman method. The results of X-ray diffraction by the Lave and XRD methods showed that the obtained crystal was grown as a uniform single crystal along the [001] crystallographic direction. The Curie temperature of the single crystal sample was 150 °C, which was extracted by measuring the dielectric constant curve as a function of temperature. Fitting the dielectric constant curve data with the modified Curie-Weiss law confirmed the relaxor behavior of this single crystal. The results of the P-E loop measurement showed that this single crystal had a coercive field of 3.5 kV/cm and a saturation electric polarization of 30 $\mu\text{C}/\text{cm}^2$. The grown single crystal had a piezoelectric charge coefficient of 1455 pC/N.

Keywords: Single Crystal, Crystal Growth, Bridgman, Relaxor Piezoelectric, Electroacoustic Transducer

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